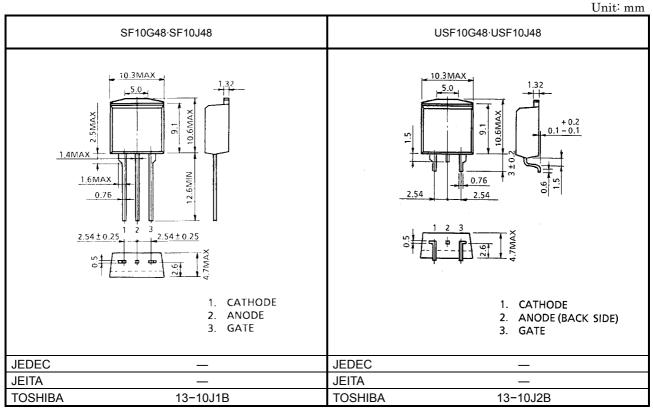
TOSHIBA THYRISTOR SILICON PLANAR TYPE

SF10G48,SF10J48,USF10G48,USF10J48

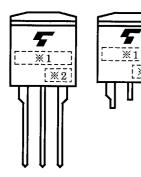
MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V_{DRM} = 400,600V
- Repetitive Peak Reverse Voltage : V_{RRM} = 400,600V
- Average On–State Current : IT (AV) = 10A
- Gate Trigger Current : I_{GT} = 10mA MAX.



Weight: 1.7g

MARKING



 $\times 2$

*1	MARK	F10G48	TYPE	SF10G48, USF10G48				
		F10J48	NAME	ASF10J48, USF10J48				
*2	Lot Numb	Lot Number						
	L	Year (Last Decimal Digit of the Current Year)						

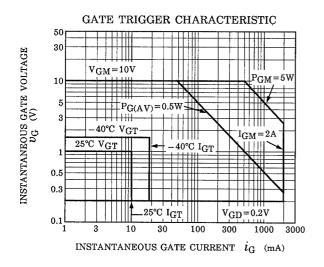
MAXIMUM RATINGS

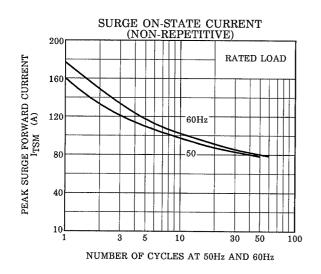
CHARACTERIS	STIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage and	SF10G48 USF10G48	V _{DRM}	400	V	
Repetitive Peak Reverse Voltage	SF10J48 USF10J48	V _{RRM}	600		
Non-Repetitive Peak Reverse Voltage	SF10G48 USF10G48		500	V	
(Non−Repetitive <5ms, T _j = 0~125°C)	SF10J48 USF10J48	V _{RSM}	720	V	
Average On-State Curre	ent	I _{T (AV)}	10	А	
R.M.S On-State Current	:	I _{T (RMS)}	16	А	
Peak One Cycle Surge On-State Current (Non-Repetitive)		I _{TSM}	160 (50Hz)	А	
			176 (60Hz)	A	
I ² t Limit Value		l ² t	125	A ² s	
Critical Rate of Rise of C Current	n−State (Note 1)	di / dt	100	A / µs	
Peak Gate Power Dissip	ation	P _{GM}	5	W	
Average Gate Power Dis	sipation	P _{G (AV)}	0.5	W	
Peak Forward Gate Volta	age	V _{FGM}	10	V	
Peak Reverse Gate Volt	age	V _{RGM}	-5	V	
Peak Forward Gate Curr	ent	I _{GM}	2	А	
Junction Temperature		Tj	-40~125	°C	
Storage Temperature Ra	ange	T _{stg}	-40~125	°C	

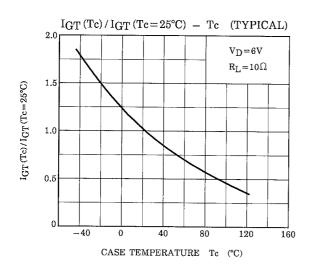
Note 1: $V_{DRM} = 0.5 \times Rated$, $I_{TM} \le 30A$, $t_{gw} \ge 10\mu s$, $t_{gr} \le 250ns$, $i_{gp} = I_{GT} \times 2.0$

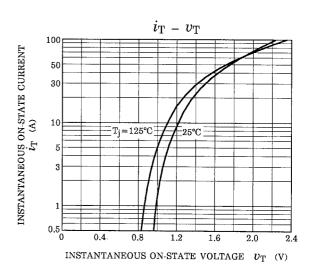
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

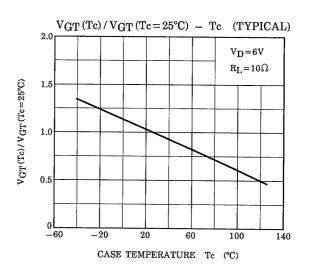
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	10	μA
Peak On-State Voltage	V _{TM}	I _{TM} = 30A	_		1.5	V
Gate Trigger Voltage	V _{GT}	V _D = 6V, R _I = 10Ω	_	-	1.0	V
Gate Trigger Current	I _{GT}	$v_{\rm D} = 0v, \kappa_{\rm L} = 10s_2$	_	_	10	mA
Gate Non-Trigger Voltage	V _{GD}	V _D = Rated × 2 / 3, Tc = 125°C	0.2	_	—	V
Critical Rate of Rise of Off-State Voltage	dv /dt	V _{DRM} = Rated, Tc = 125°C Exponential Rise	_	50	_	V / µs
Holding Current	Ι _Η	V _D = 6V, I _{TM} = 1A	_	-	40	mA
Latching Current	١ _L	V _D = 6V, f = 50Hz t _{gw} = 50μs, i _G = 30mA	_	_	50	mA
Thermal Resistance	R _{th (j−c)}	Junction to Case, DC	_	_	2.5	°C/W

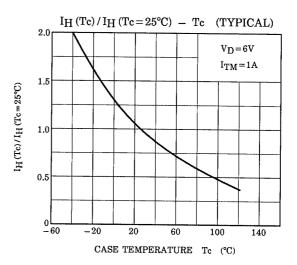


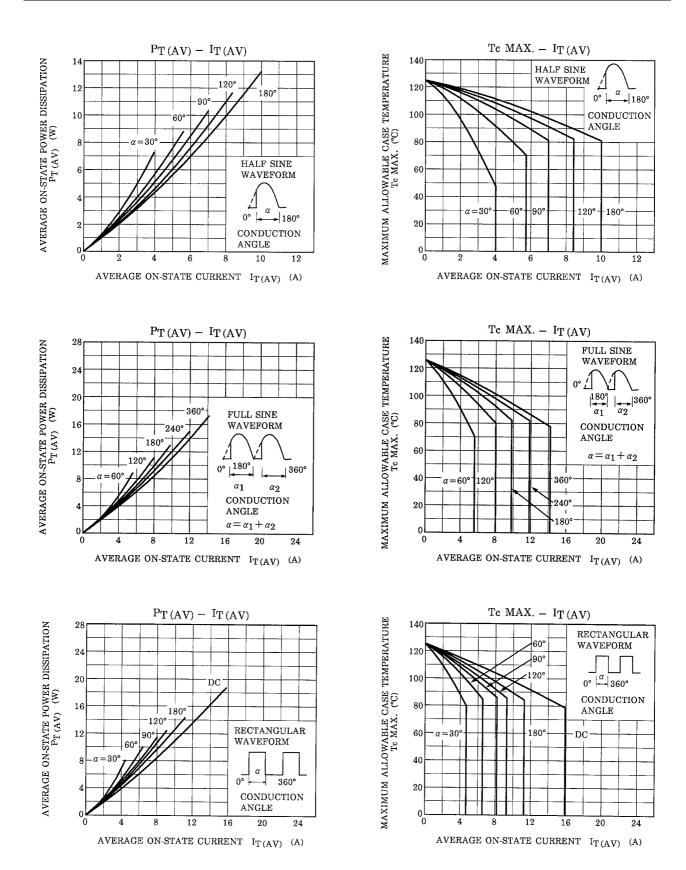




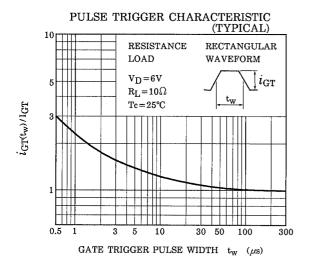


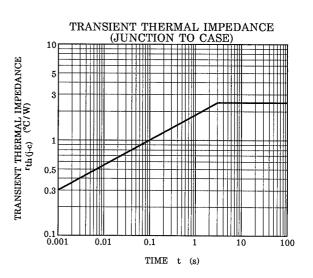






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